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- Output Voltage Translation Tracks V_{CC}
- Supports Mixed-Mode Signal Operation On All Data I/O Ports
 - 5-V Input Down To 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down To 2.5-V Output Level Shift With 2.5-V V_{CC}
- 5-V-Tolerant I/Os With Device Powered Up or Powered Down
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics (r_{on} = 5 Ω Typical)
- Low Input/Output Capacitance Minimizes Loading (Cio(OFF) = 8 pF Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I_{CC} = 20 μA Max)

- V_{CC} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Performance Tested Per JESD 22

 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level Translation, Memory Interleaving, Bus Isolation
- Ideal for Low-Power Portable Equipment

DBQ, DGV, DW, OR PW PACKAGE (TOP VIEW)

	_		
BE	[1	U ₂₄] v _{cc}
1B1	2	23	5B2
1A1	[] 3	22	5A2
1A2	4	21	5A1
1B2	5	20	5B1
2B1	6	19	4 B2
2A1	[7	18	4A2
2A2	8	17	4A1
2B2	9	16	4 B1
3B1	10	15	3B2
3A1	11	14	3A2
GND	12	13] вх

description/ordering information

ORDERING INFORMATION

TA	PACKAGE	±†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	0010 014	Tube	SN74CB3T3383DW	ODOTOOOO	
	SOIC – DW	Tape and reel	SN74CB3T3383DWR	CB3T3383	
-40°C to 85°C	SSOP (QSOP) – DBQ	DBQ Tape and reel SN74CB3T3383DBQR		CB3T3383	
-40 C 10 85 C	TOCOD DW	Tube	SN74CB3T3383PW	140000	
	TSSOP – PW	Tape and reel	SN74CB3T3383PWR	KS383	
	TVSOP – DGV	Tape and reel	SN74CB3T3383DGVR	KS383	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

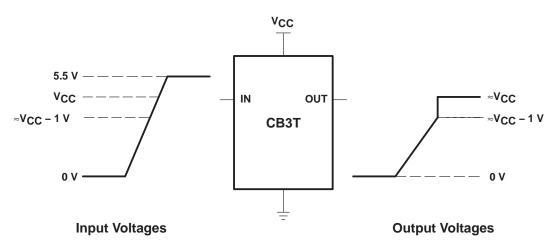


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description/ordering information (continued)

The SN74CB3T3383 is a high-speed TTL-compatible FET bus-exchange switch with low ON-state resistance (ron), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC}. The SN74CB3T3383 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).



NOTE A: If the input high voltage (VIH) level is greater than or equal to V_{CC} - 1 V, and less than or equal to 5.5 V, then the output high voltage (VOH) level will be equal to approximately the VCC voltage level.

Figure 1. Typical DC Voltage Translation Characteristics

The SN74CB3T3383 is organized as a 10-bit bus switch or as a 5-bit bus-exchange with enable (BE) input. When used as a 5-bit bus-exchange, the device provides data exchanging between four signal ports. When BE is low, the bus-exchange switch is ON, and the select input (BX) controls the data path. When BE is high, the bus-exchange switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using Ioff. The Ioff feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

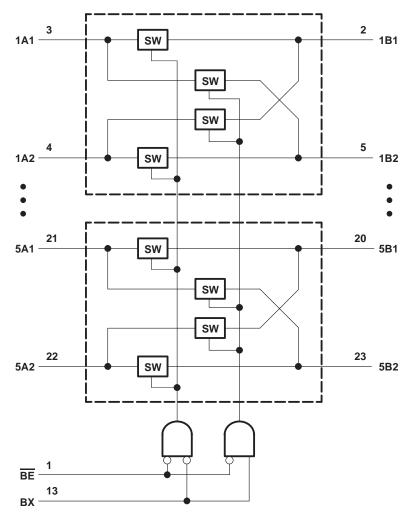
To ensure the high-impedance state during power up or power down, BE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



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ſ	INP	UTS	INPUTS/	OUTPUTS	
ĺ	BE	вх	A1	A2	FUNCTION
	L	L	B1	B2	A1 port = B1 port A2 port = B2 port
	L	Н	B2	B1	A1 port = B2 port A2 port = B1 port
	Н	Х	Z	Z	Disconnect

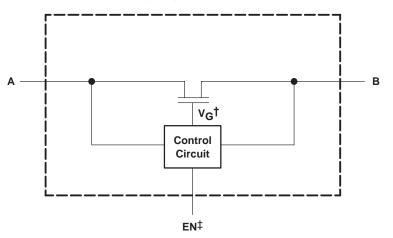
logic diagram (positive logic)





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simplified schematic, each FET switch (SW)



[†] Gate Voltage (V_G) is approximately equal to V_{CC} + V_T when the switch is ON and V_I > V_{CC} + V_T. [‡] EN is the internal enable signal applied to the switch.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)§

Supply voltage range, V _{CC} (see Note 1)	/
Control input voltage range, VIN (see Notes 1 and 2)	/
Switch I/O voltage range, V _{I/O} (see Notes 1, 2, and 3)	/
Control input clamp current, I _{IK} (V _{IN} < 0)	١
I/O port clamp current, I _{I/OK} (V _{I/O} < 0)	٩.
ON-state switch current, II/O (see Note 4) ±128 mA	٩.
Continuous current through V _{CC} or GND terminals	٩.
Package thermal impedance, θ _{JA} (see Note 5): DBQ package	Ι
DGV package	/
DW package	/
PW package	/
Storage temperature range, T _{stg})

§ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.
 - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 3. VI and VO are used to denote specific conditions for $V_{I/O}$.
 - 4. I and I are used to denote specific conditions for $I_{I/O}$.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 6)

			MIN	MAX	UNIT
VCC	Supply voltage		2.3	3.6	V
N	LP-shi based a sector D-sector setter as	V_{CC} = 2.3 V to 2.7 V	1.7	5.5	
VIH	High-level control input voltage	V _{CC} = 2.7 V to 3.6 V	2	5.5	V
	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0	0.7	
VIL	Low-level control input voltage	$V_{CC} = 2.7 V \text{ to } 3.6 V$	0	0.8	V
V _{I/O}	Data input/output voltage		0	5.5	V
TA	Operating free-air temperature		-40	85	°C

NOTE 6: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CON	MIN	TYP†	MAX	UNIT	
VIK		$V_{CC} = 3 V,$ $I_{I} = -18 mA$				-1.2	V
VOH		See Figures 3 and 4					
I _{IN} ‡	Control inputs	$V_{CC} = 3.6 V,$ $V_{IN}^{\ddagger} = 3.6 V \text{ to } 5.5 V \text{ or GND}$				±10	μΑ
	-	$V_{\rm CC} = 3.6 \text{V},$	$V_{I} = V_{CC} - 0.7 V \text{ to } 5.5 V$			±20	
l _i		Switch ON,	V_{I} = 0.7 V to V_{CC} – 0.7 V			-40	μΑ
		$V_{IN} = V_{CC}$ or GND	$V_{I} = 0$ to 0.7 V			±5	
I _{OZ} §					±10	μΑ	
l _{off}		$V_{CC} = 0,$ $V_{O} = 0$ to 5.5 V, $V_{I} = 0,$				10	μΑ
	$V_{CC} = 3.6 V,$ $I_{I/O} = 0,$		$V_I = V_{CC}$ or GND	20		20	
ICC		Switch ON or OFF, $V_{IN} = V_{CC}$ or GND	VI = 5.5 V	20		20	μA
∆ICC¶	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND			300	μΑ	
C _{in}	Control inputs	$V_{CC} = 3.3 V,$ $V_{IN} = V_{CC} \text{ or GND}$			4		pF
C _{io(OFF})	$V_{CC} = 3.3 \text{ V},$ $V_{I/O} = 5.5 \text{ V}, 3.3 \text{ V}, \text{ or GND},$ Switch OFF, $V_{IN} = V_{CC} \text{ or GND}$			8		pF
		$V_{CC} = 3.3 V,$ Switch ON,	V _{I/O} = 5.5 V or 3.3 V		7		pF
C _{io(ON)}	$V_{IN} = V_{CC}$ or GND		V _{I/O} = GND		21		P1
		$V_{CC} = 2.3 V,$ TYP at $V_{CC} = 2.5 V,$	I _O = 24 mA			9	
ron [#]		$V_{I} = 0$	I _O = 16 mA		5	9	Ω
511		V _{CC} = 3 V,	I _O = 64 mA		5	8	
$V_{I} = 0$			I _O = 32 mA		5	8	

[†] All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C. [‡] V_{IN} and I_{IN} refer to control inputs. V_I, V_O, I_I, and I_O refer to data pins. § For I/O ports, the parameter I_{OZ} includes the input leakage current.

This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.



SN74CB3T3383 **10-BIT FET BUS-EXCHANGE SWITCH** 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER SCDS158A - OCTOBER 2003 - REVISED DECEMBER 2004

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

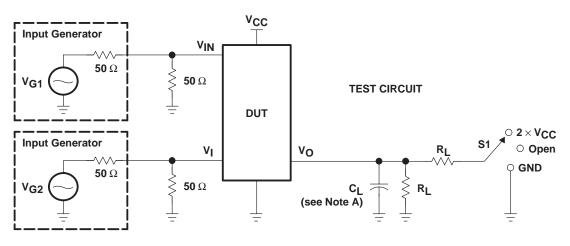
PARAMETER	FROM (INPUT)	TO	۷ _{CC} = ± 0.2	2.5 V 2 V	V _{CC} = ± 0.3	UNIT	
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
t _{pd} †	A or B	B or A		0.15		0.25	
^t pd(s)	BX	A or B	1	15	1	10	ns
^t en	BE	A or B	1	13.5	1	9	ns
^t dis	BE	A or B	1	7	1	8.5	ns

[†] The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

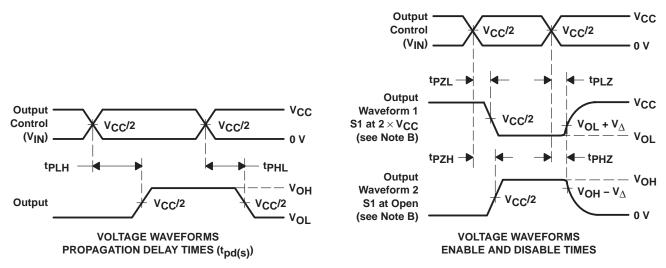


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PARAMETER MEASUREMENT INFORMATION



TEST	VCC	S1	RL	VI	сL	v_Δ
^t pd(s)	$\begin{array}{c}\textbf{2.5 V}\pm\textbf{0.2 V}\\\textbf{3.3 V}\pm\textbf{0.3 V}\end{array}$	Open Open	500 Ω 500 Ω	3.6 V or GND 5.5 V or GND	30 pF 50 pF	
^t PLZ ^{/t} PZL	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	$\begin{array}{c} 2 \times \mathbf{V_{CC}} \\ 2 \times \mathbf{V_{CC}} \end{array}$	500 Ω 500 Ω	GND GND	30 pF 50 pF	0.15 V 0.3 V
tPHZ/tPZH	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	Open Open	500 Ω 500 Ω	3.6 V 5.5 V	30 pF 50 pF	0.15 V 0.3 V

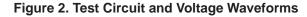


NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns. t_f \leq 2.5 ns.

- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.





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TYPICAL CHARACTERISTICS

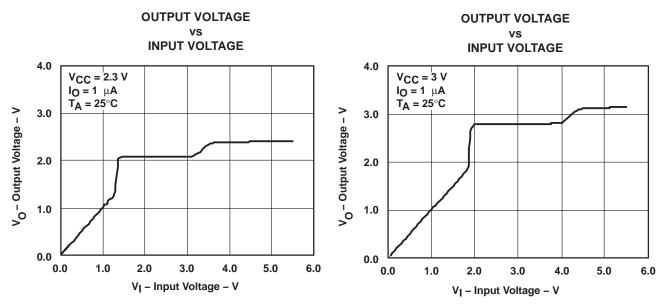


Figure 3. Data Output Voltage vs Data Input Voltage



SN74CB3T3383 10-BIT FET BUS-EXCHANGE SWITCH 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER SCDS158A – OCTOBER 2003 – REVISED DECEMBER 2004

OUTPUT VOLTAGE HIGH OUTPUT VOLTAGE HIGH vs vs SUPPLY VOLTAGE SUPPLY VOLTAGE 4.0 4.0 V_{CC} = 2.3 V to 3.6 V V_{CC} = 2.3 V to 3.6 V V_{OH} - Output Voltage High - V $V_{I} = 5.5 V$ V_{OH} - Output Voltage High - V V_I = 5.5 V **100 μA** T_A = 85°C 3.5 T_A = 25°C **100 µA** 3.5 8 mÅ 8 mÅ 16 mA 24 mA 16 mA 3.0 24 mA 3.0 2.5 2.5 2.0 2.0 1.5 1.5 2.3 2.5 2.7 2.9 3.1 3.3 3.5 3.7 2.3 2.5 2.7 2.9 3.1 3.3 3.5 3.7 V_{CC} – Supply Voltage – V V_{CC} – Supply Voltage – V

TYPICAL CHARACTERISTICS (continued)



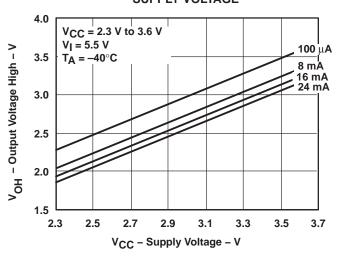


Figure 4. V_{OH} Values





24-Apr-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74CB3T3383DGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	KS383	Samples
SN74CB3T3383DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T3383	Samples
SN74CB3T3383DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T3383	Samples
SN74CB3T3383PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	KS383	Samples
SN74CB3T3383PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	KS383	Samples
SN74CB3T3383PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	KS383	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

24-Apr-2015

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3T3383DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CB3T3383DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CB3T3383PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

12-Aug-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3T3383DGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0
SN74CB3T3383DWR	SOIC	DW	24	2000	367.0	367.0	45.0
SN74CB3T3383PWR	TSSOP	PW	24	2000	367.0	367.0	38.0

MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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